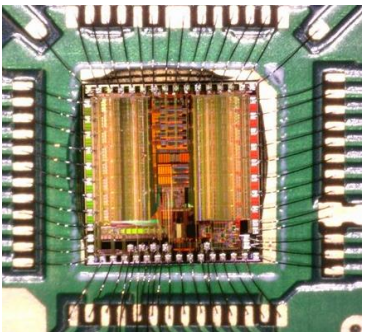
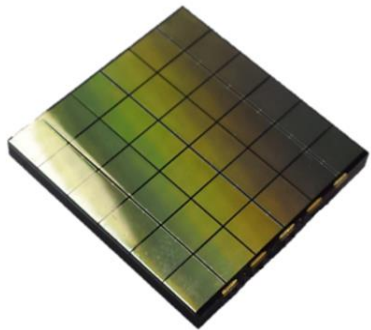
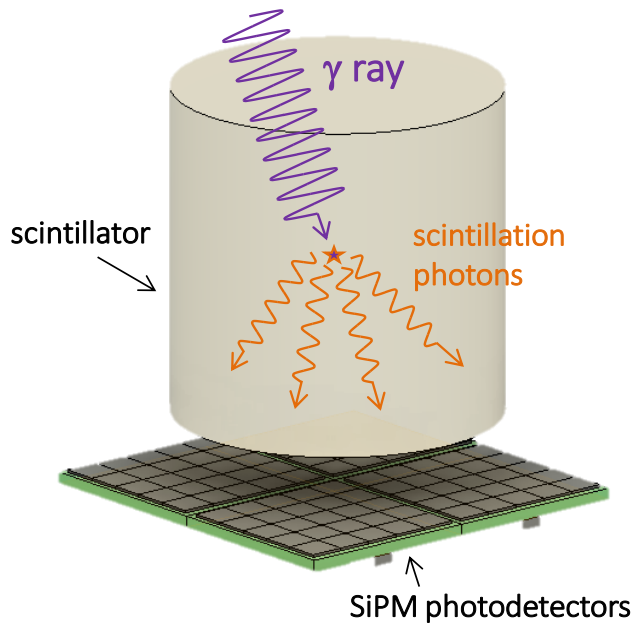




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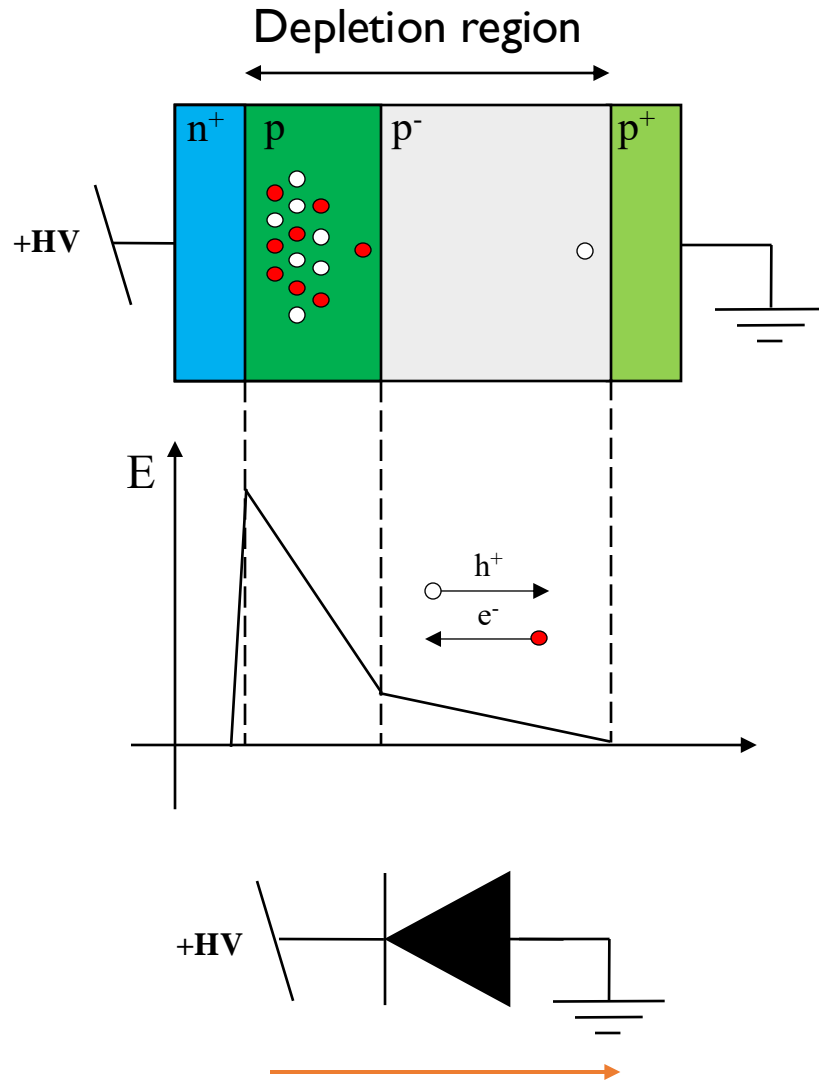


Readout of large scintillators by SiPMs and high-dynamic-range ASICs

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Istituto Nazionale di Fisica Nucleare (INFN) - Sezione di Milano, Milano, Italy

Impact Ionization in a pn diode

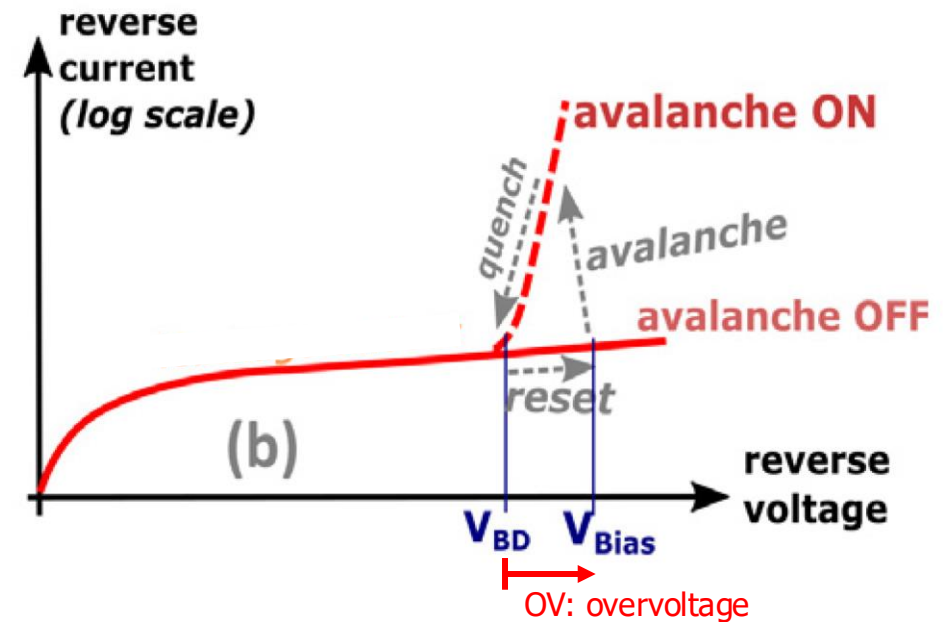
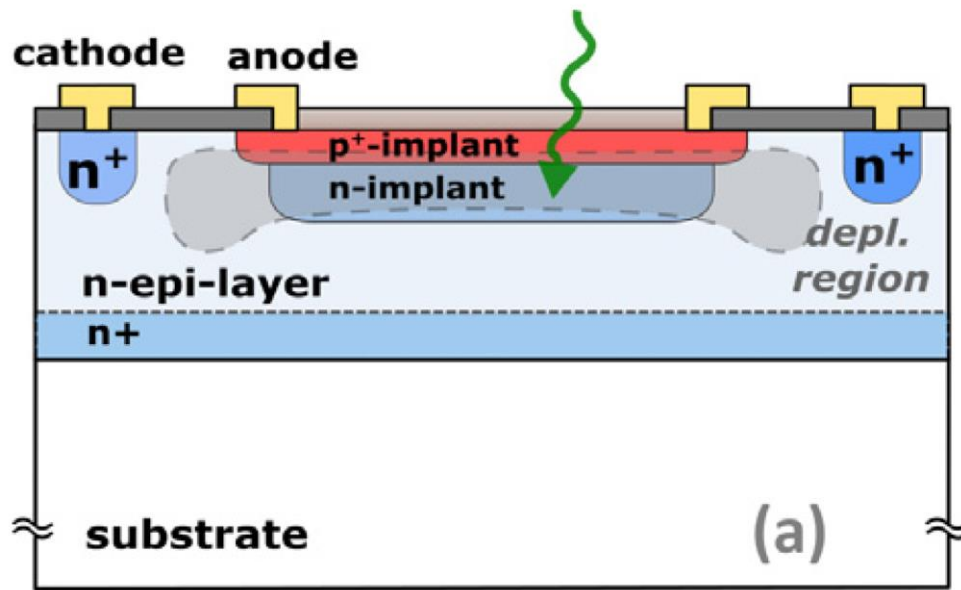


- **High electric field** ($>5 \times 10^5$ V/cm) in the depletion region
- Charge carrier can be accelerated to create secondary charge pairs through **impact ionization**.

Two different working regimes, depending on the applied voltage to the reverse biased diode:

- **APD** (Avalanche photodiode): **the output current is proportional to the input signal**
- **SPAD** (Single Photon APD) or GM-APD (Geiger Mode APD): **the output current is independent from the input signal**

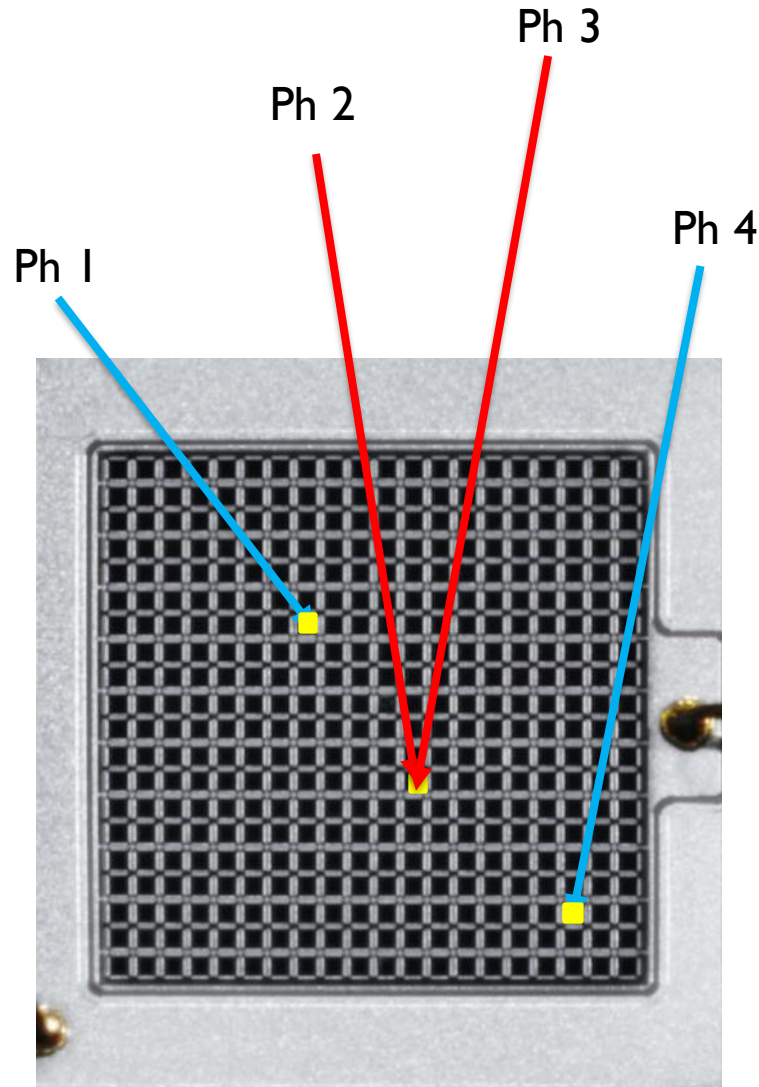
SPAD operation



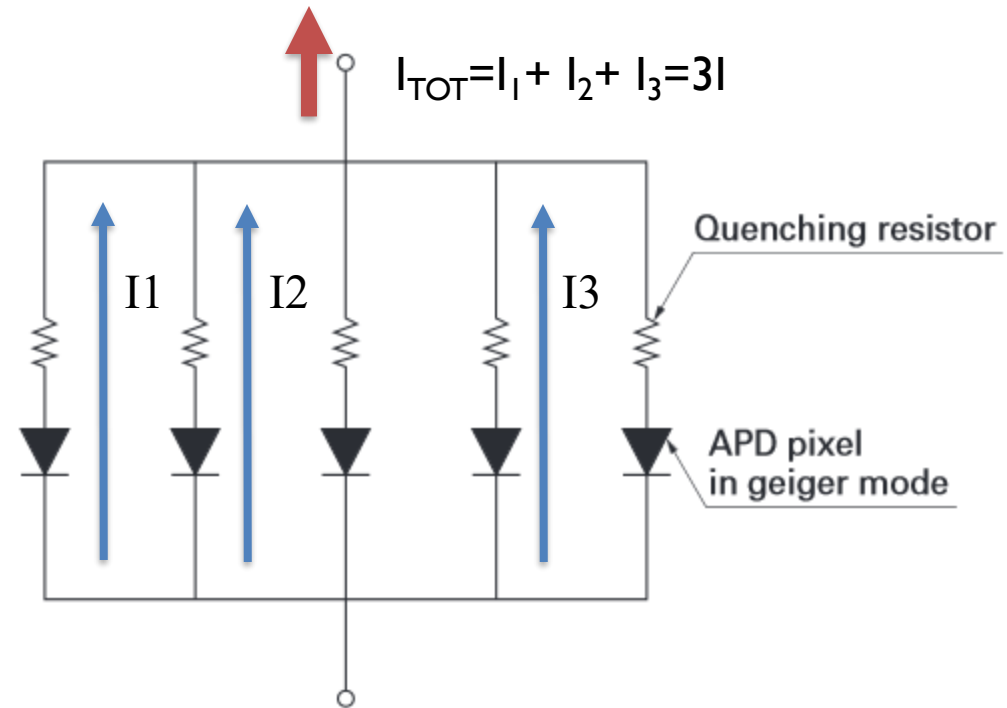
The SPAD is biased above the breakdown voltage (V_{BD}). In such conditions, the electric field is so high that a single carrier generated into the depletion layer (by an incoming photon or by thermal generation) can trigger a self-sustaining avalanche process and a rapid increase of the current to a macroscopic level.

The current theoretically would continue to flow until the avalanche is quenched by lowering the bias voltage to or below the breakdown voltage, by a so called "quenching circuit". The bias voltage (V_{bias}) must then be restored in order to be able to detect another photon (reset phase).

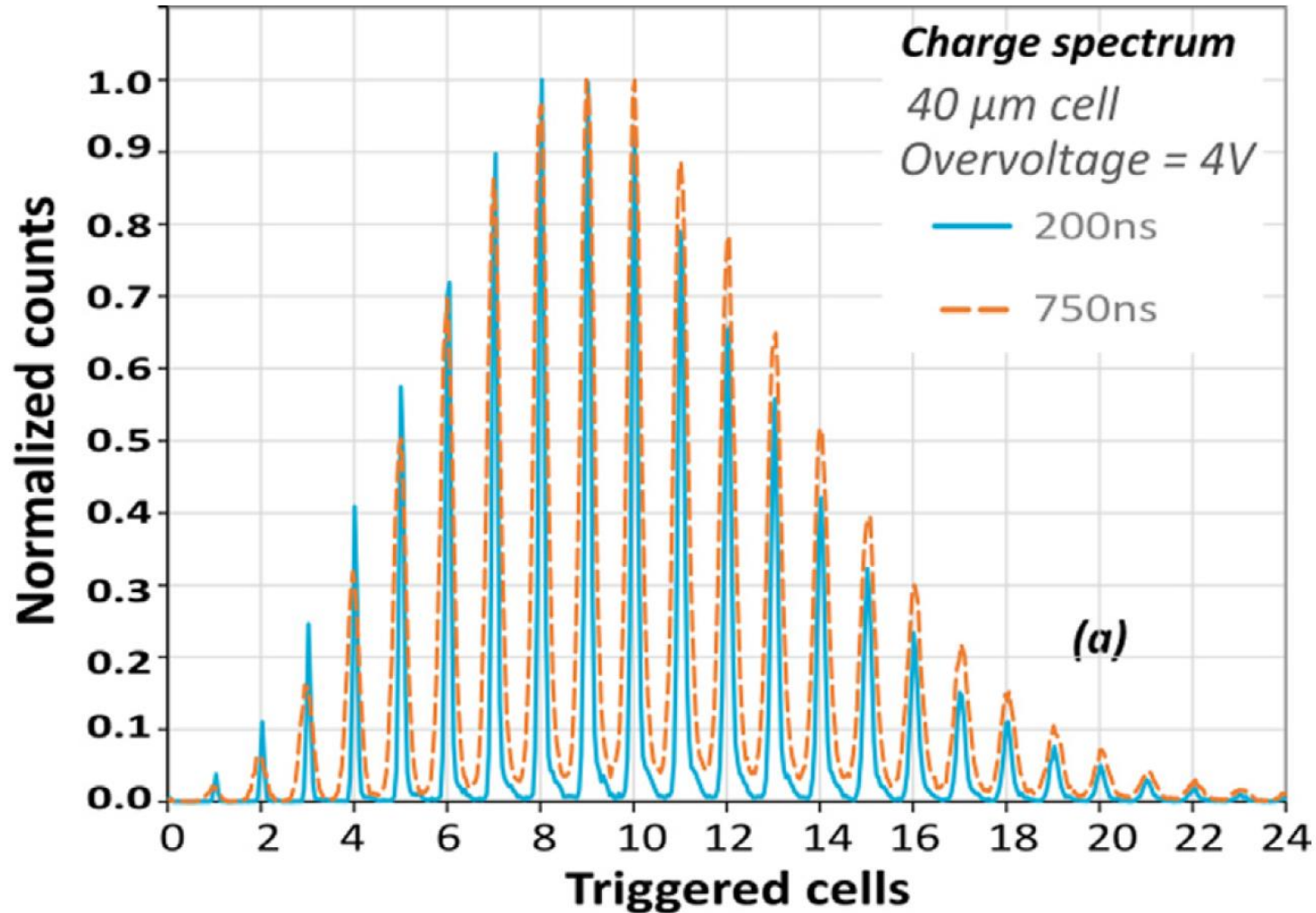
The Silicon Photomultiplier (SiPM) principle



- **Many SPAD cells in parallel** with quench resistors
- The total signal is proportional to the number of fired cells, i.e. to the number of detected photons
- Measuring the 'analog' information of I_{TOT} allows to retrieve the **number of photons absorbed**
- Multiple photons interacting on the same cell are counted as a single hit



Example of single photon detection capability



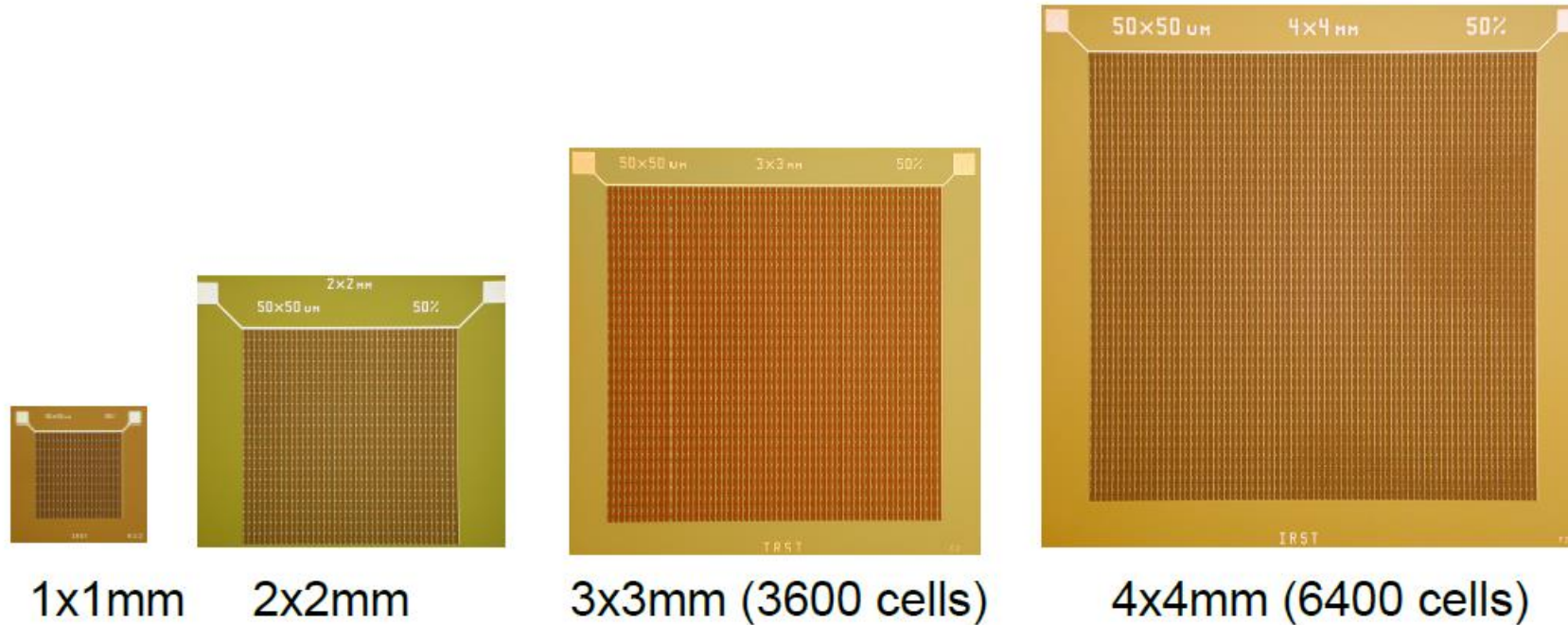
SiPMs (several producers: Hamamatsu, ON-Semi, FBK, ...)

These devices are called in different ways:

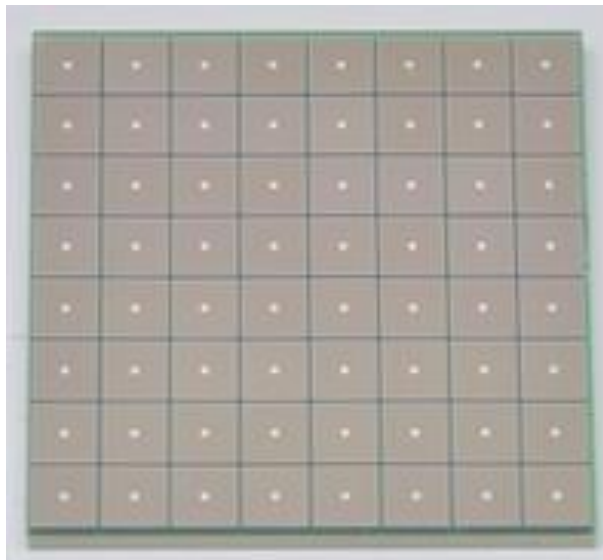
- **SiPM: Silicon Photo Multipliers**
- MPPC: Multi-Photon Pixel Counter
- Si-SSPMT: Silicon Solid State PMT

Typical SPAD cell size from $15\ \mu\text{m} \times 15\ \mu\text{m}$ up to $100\ \mu\text{m} \times 100\ \mu\text{m}$

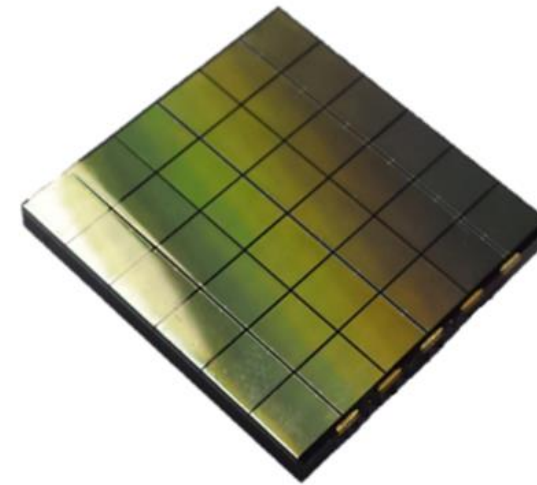
More and more alternative of Photo-Multiplier Tubes (SiPMs are more compact and MR compatible)



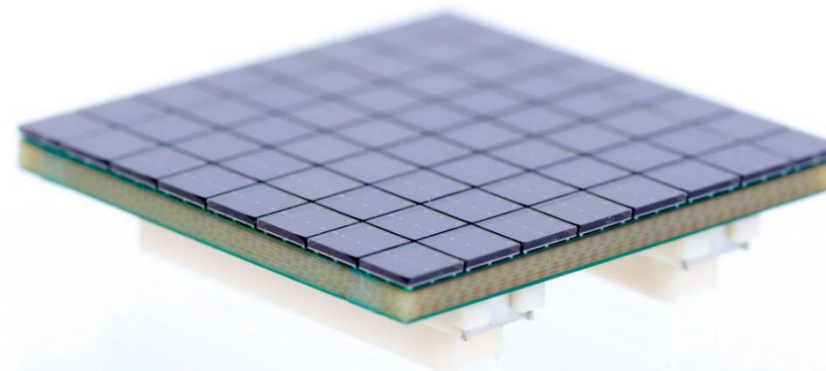
- Arrays of SiPM for Imaging applications
- Compact alignment of SiPMs
- Reduced dead area
- Common bias strategies
- Titable on 4 sides (Possibility to create larger matrices by combining single units)
- TSV (Through Silicon Via) technology



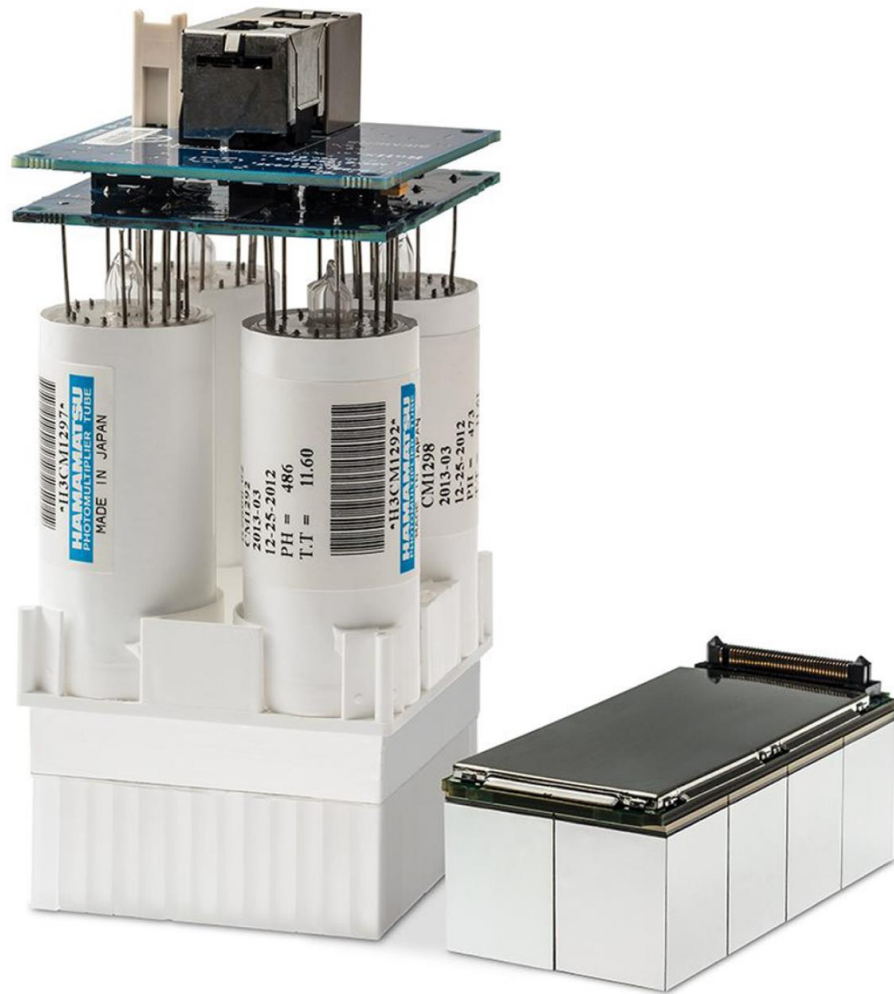
8 x 8 matrix – Hamamatsu



6 x 6 matrix - FBK



12 x 12 matrix – ON Semiconductor



Different scintillator readout configurations:

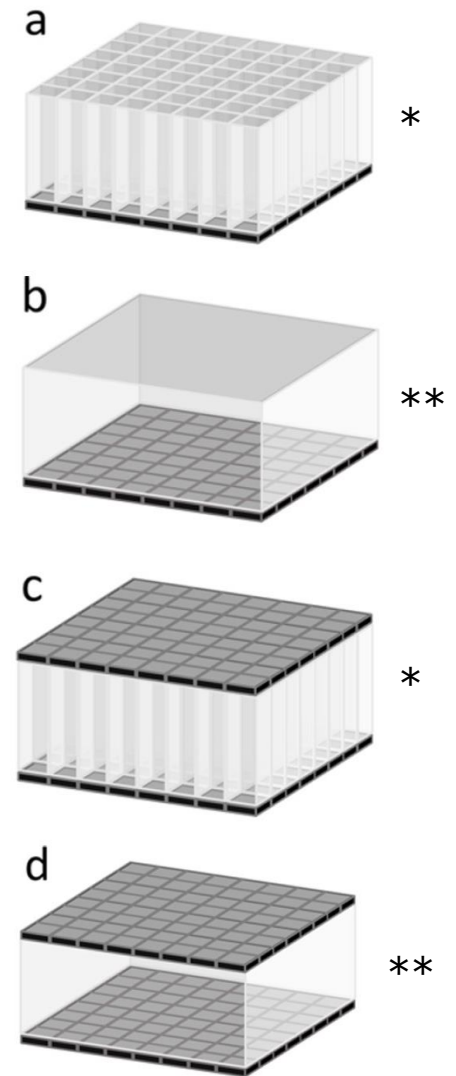
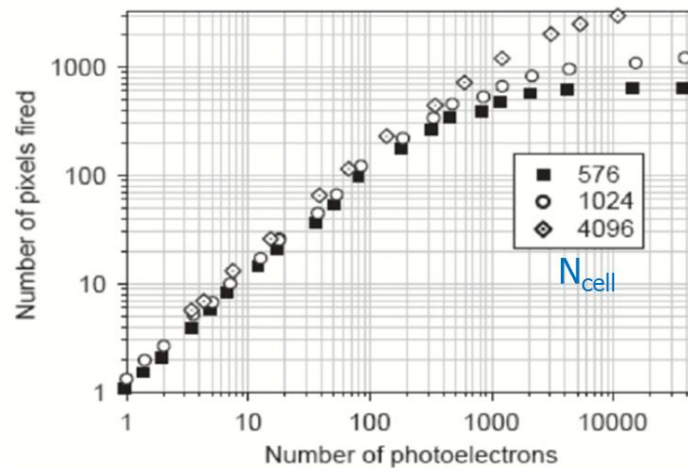
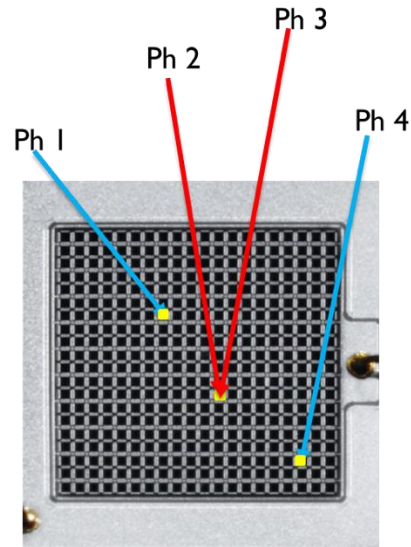
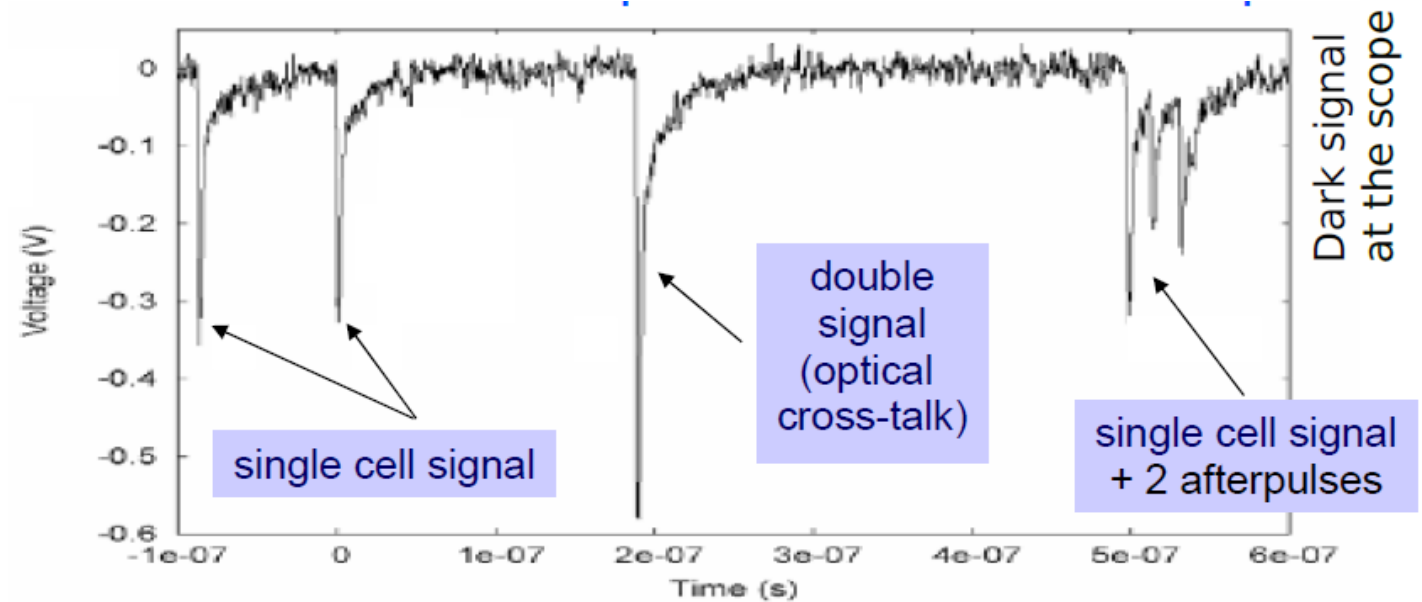


Fig. 2. Picture showing the comparison of PET detectors based on PMTs (left) and on SiPMs (right) in their implementation by Siemens Healthineers (picture from [34]).

1) Dynamic Range



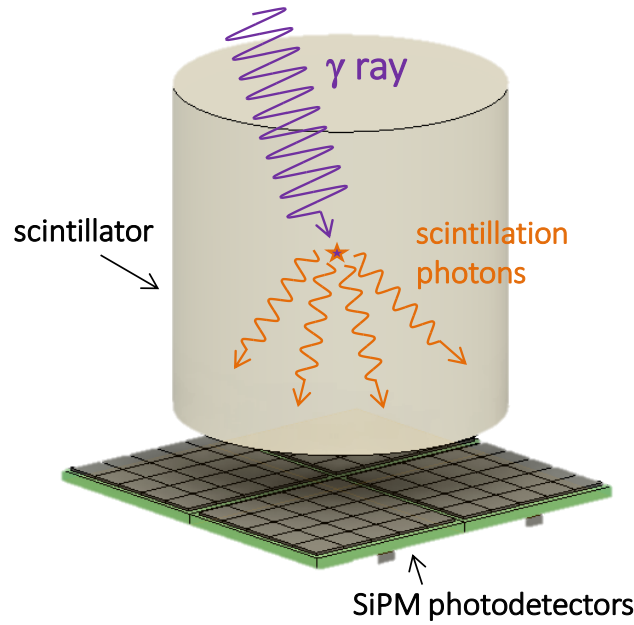
2) Noise



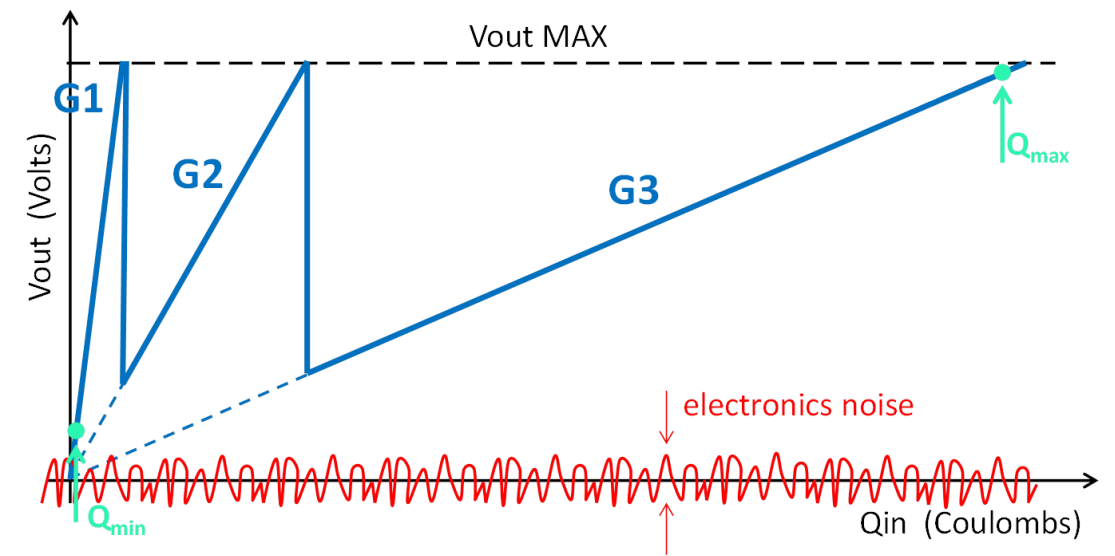
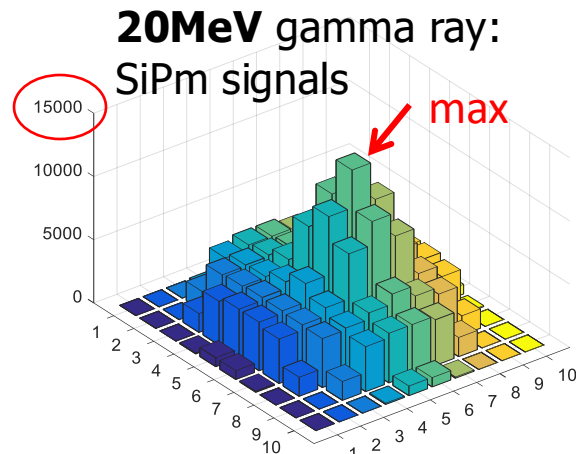
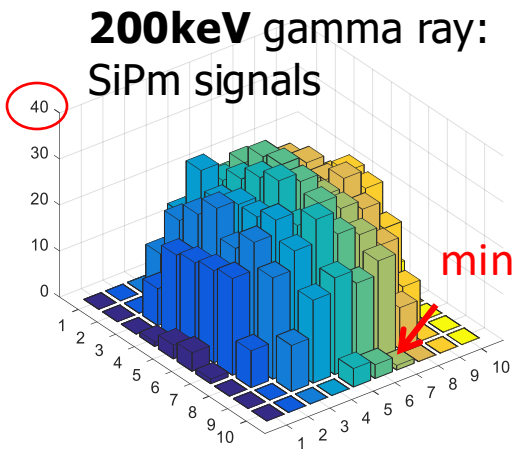
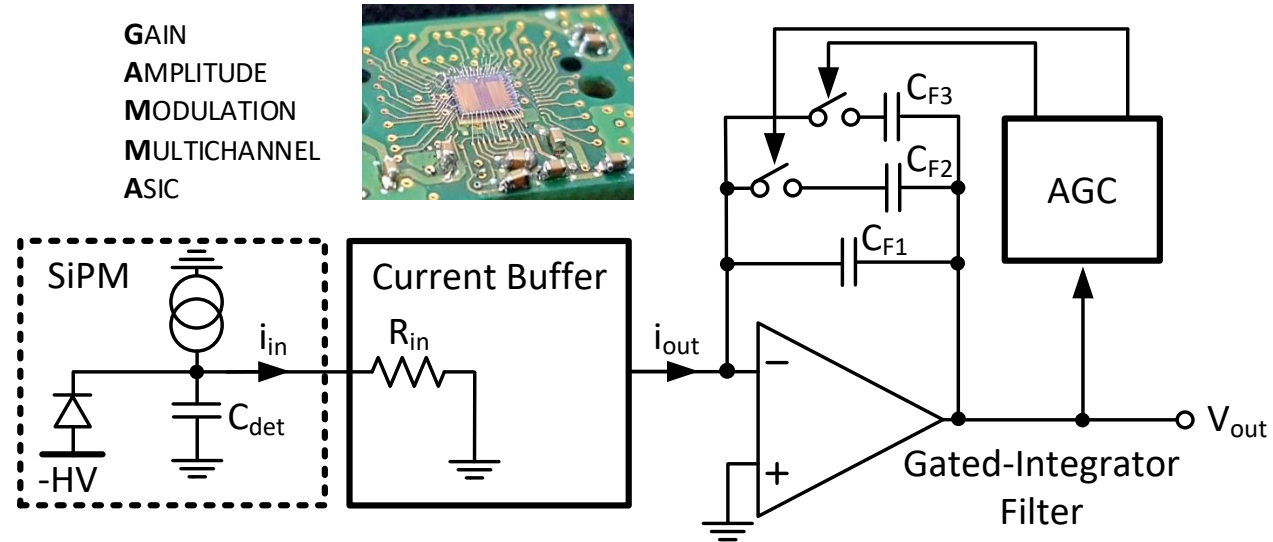
- Primary source: **Dark count**
- Secondary sources: **After pulse, Cross talk**

3) Small pixels → to cover large areas, need for a readout ASIC

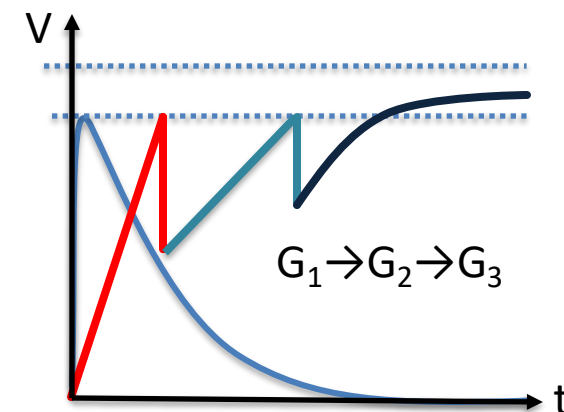
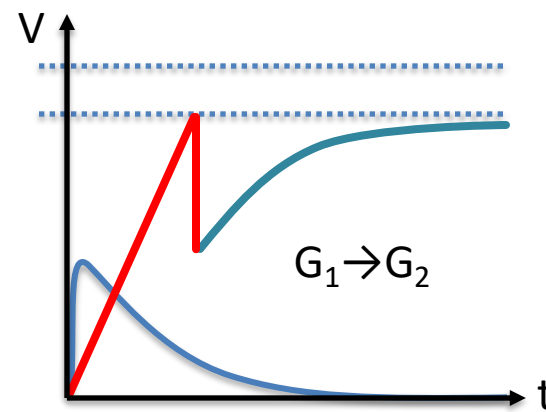
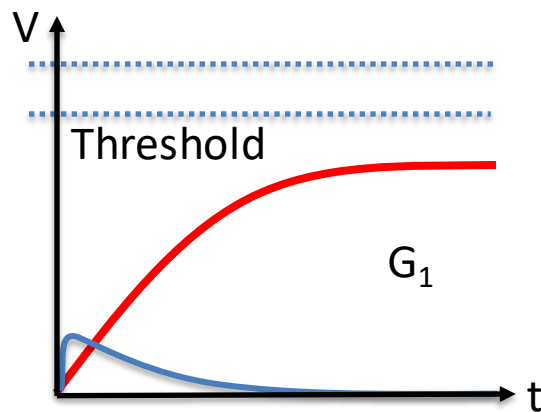
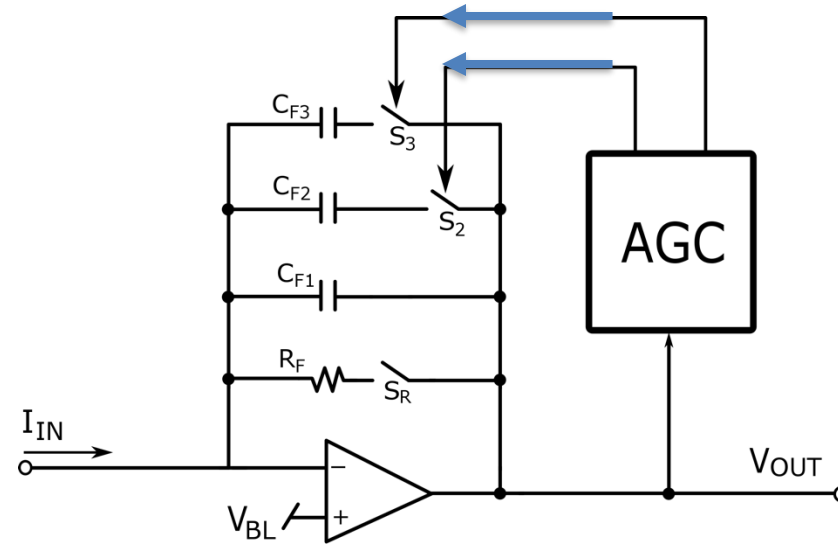
Automatic Gain Control (AGC) ASIC to cover a high dynamic range (1ph→10.000ph) in γ -spectroscopy

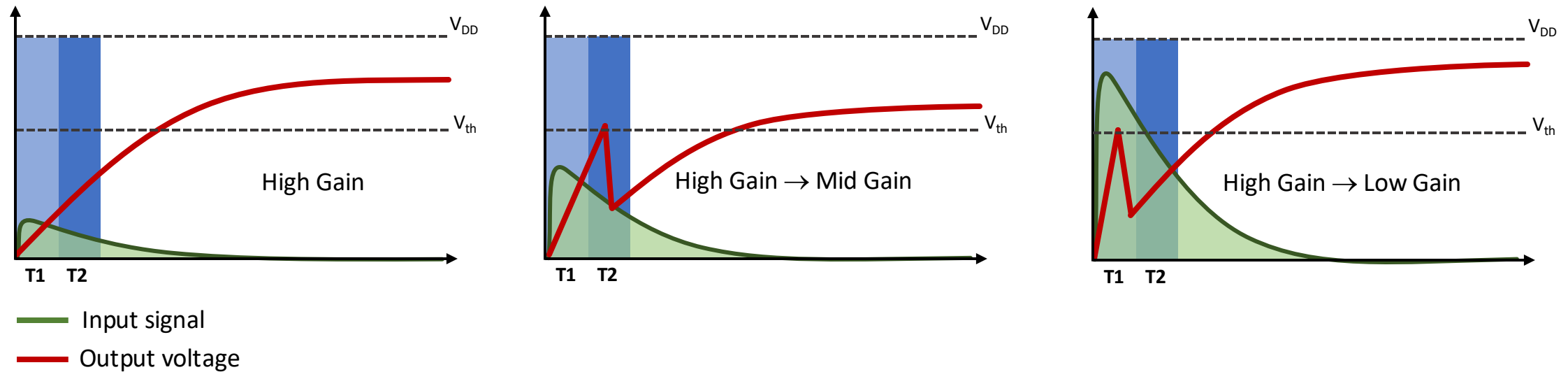


High-dynamic range gamma detectors



Gain-switching: standard approach

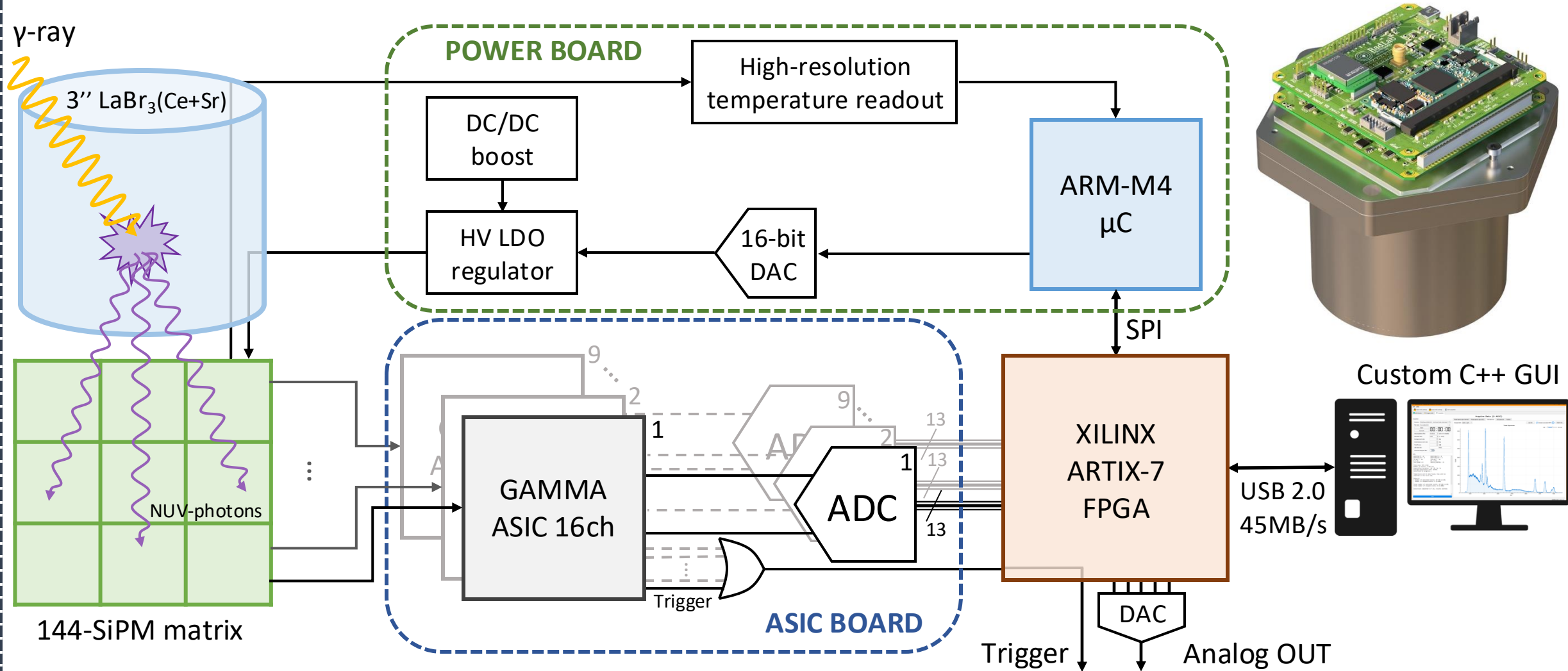




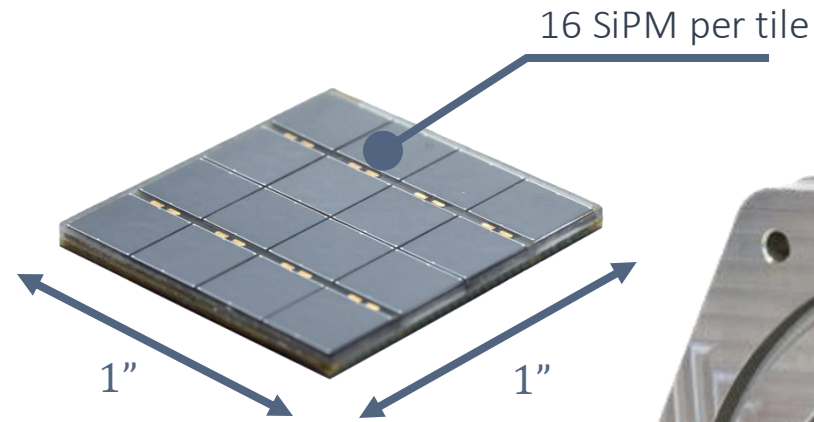
Features:

- Only one gain transition among multiple gains
- Relative freedom in setting the threshold
- Gain-switch decision taken quite early vs. end of integration
- Gain modulation allows for 84dB Dynamic Range on each channel!

The GAMMA detector - General architecture



- 6 x 6 mm² SiPMs
- 9 tiles, 1" x 1" size each, 4-side buttable
- Custom high-reliability connectors
- Temperature sensor under each tile



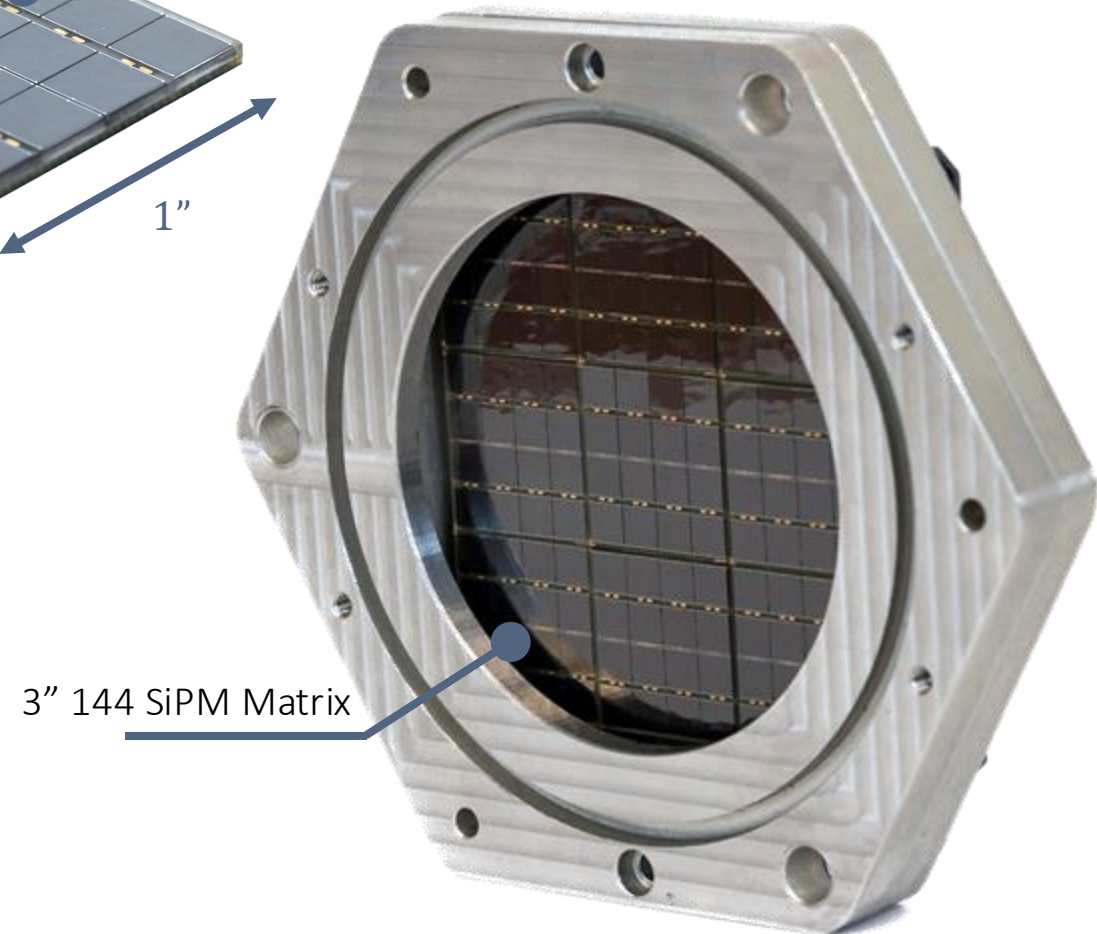
Two microcell options: 30 μ m and 15 μ m cells

30 μ m cells:

- 45% PDE
- 77% FF
- $V_{BD} = 26.5V$
- 40kHz/mm² DCR
- 1% non-linearity due to cell saturation at 9 MeV, 4% at 15.1 MeV
- 30 MeV FSR

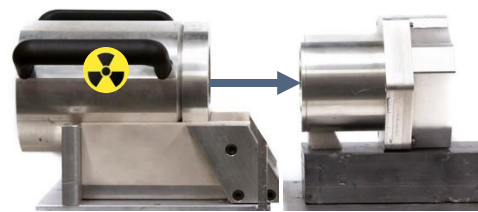
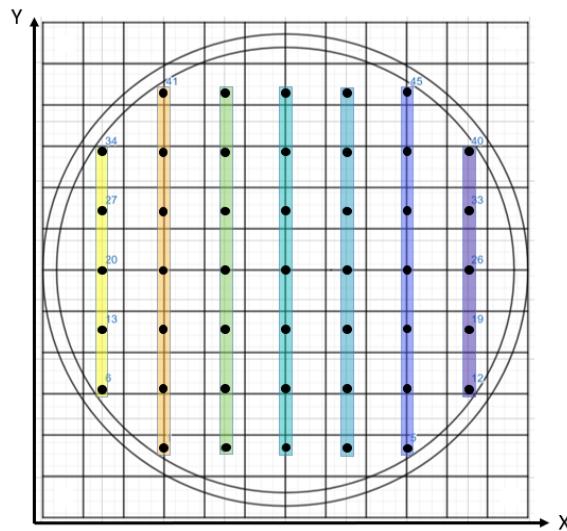
15 μ m cells:

- 40% PDE
- 61% FF
- $V_{BD} = 31.5V$
- 60kHz/mm² DCR
- 1% non-linearity due to cell saturation at 35 MeV
- > 50 MeV FSR

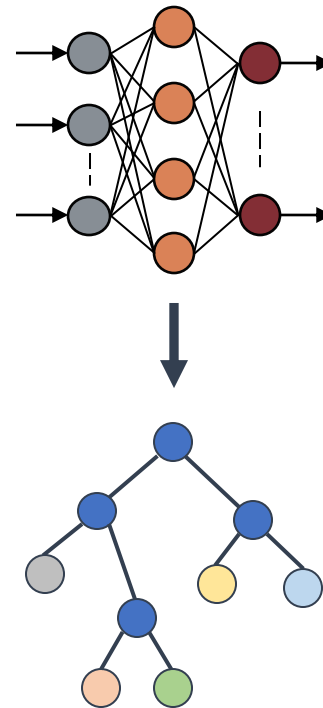


Training dataset

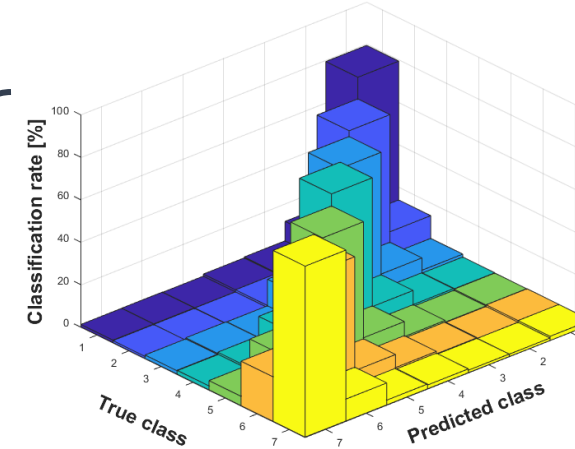
- 45 spots (1cm spaced)
- 7 classes (1D-reconstruction)



NN filter + DT classifier



Confusion matrix (1D)

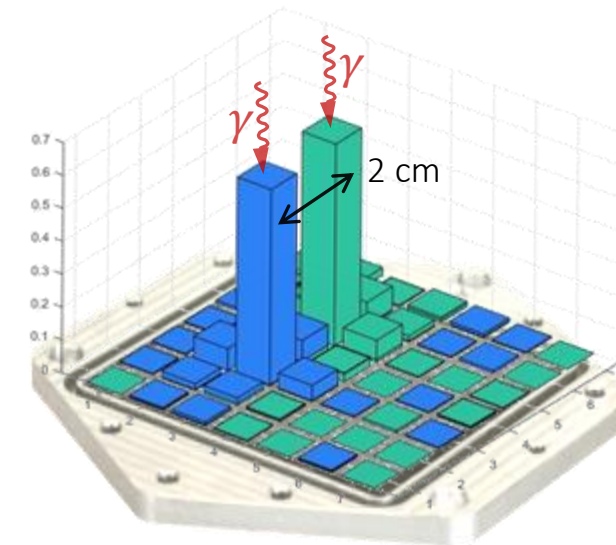


Decision Tree

- Mean error: 0.47cm
- RMS error: 1.08cm

Neural Network

- Mean error: 0.42cm
- RMS error: 1.02cm

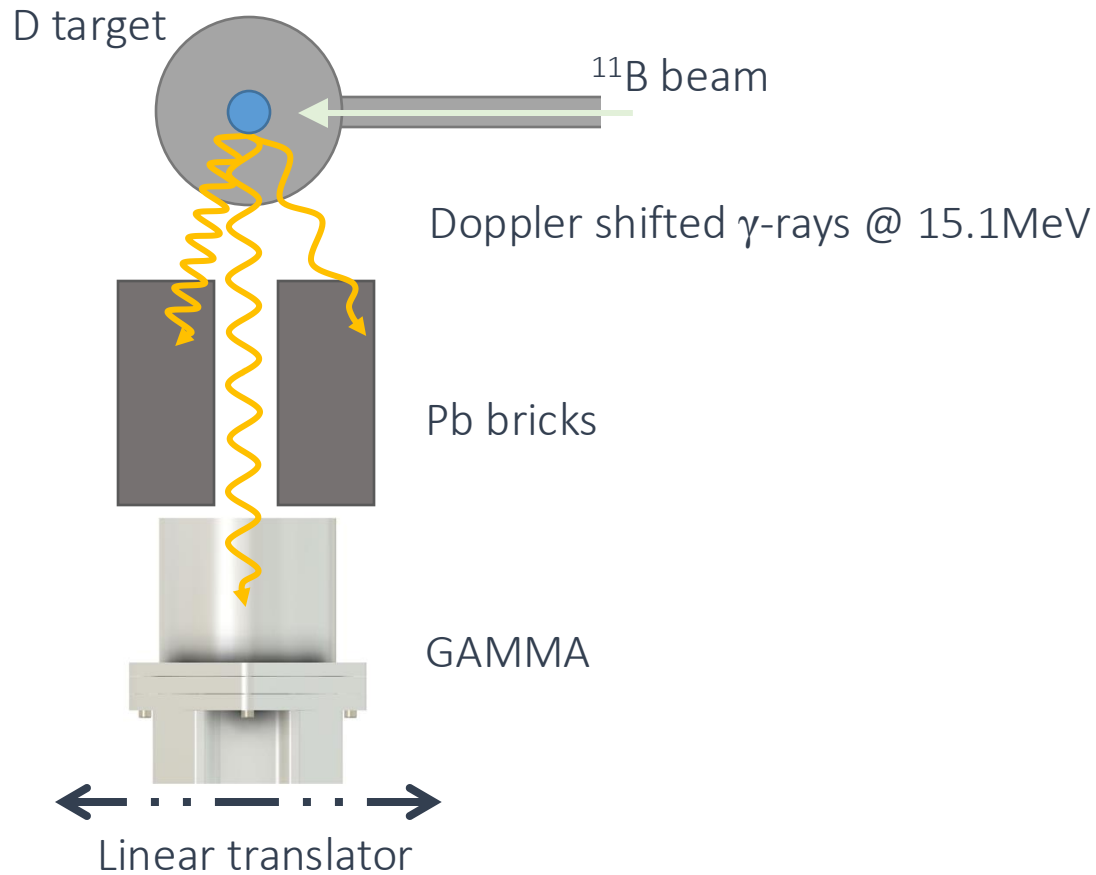


2cm spaced irradiations

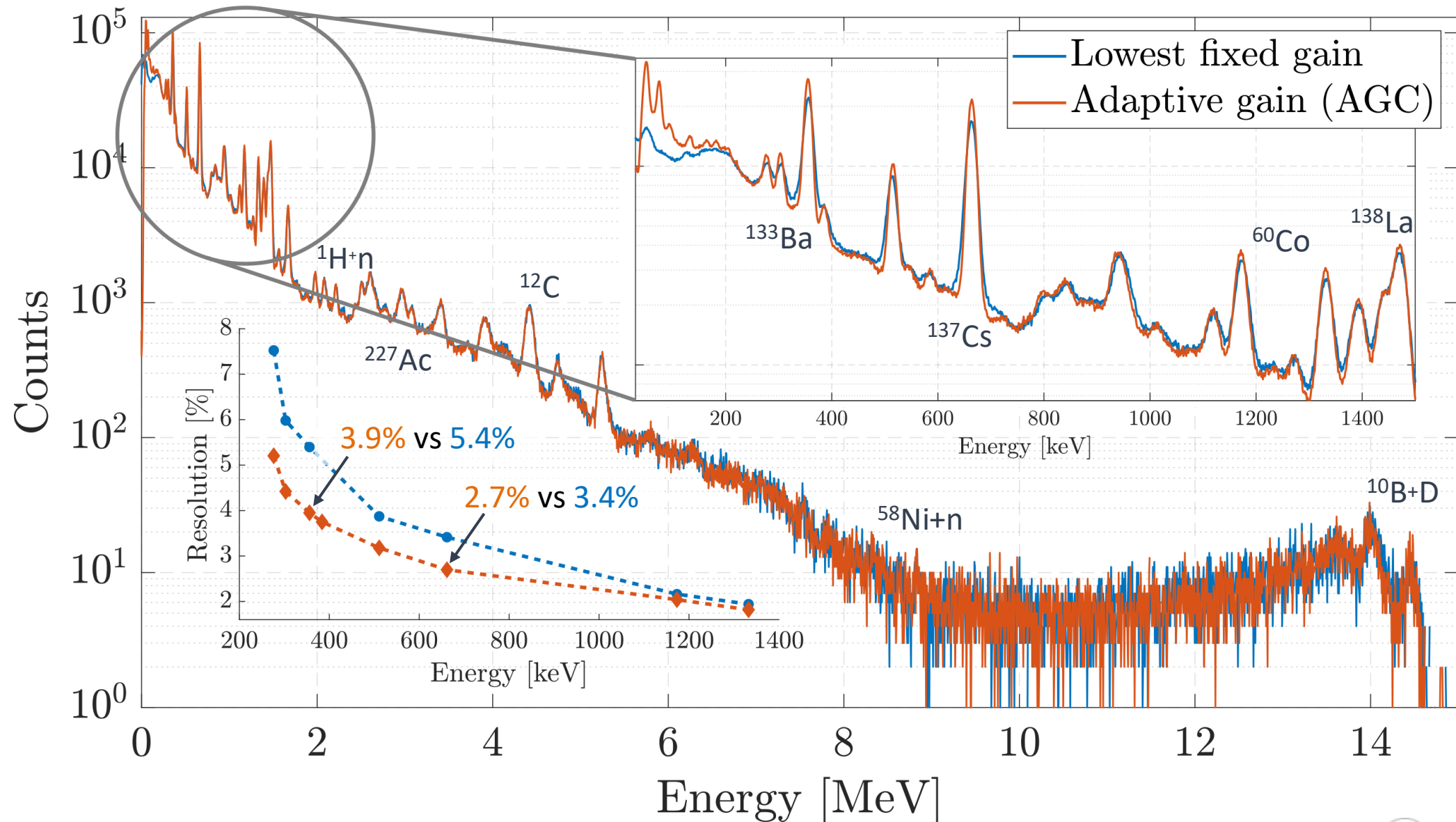
G. Ticchi, L. Buonanno, D. Di Vita, et al., "Embedded Artificial Intelligence for Position Sensitivity in Thick Scintillators," *Nuclear Instruments and Methods in Physics Research Section A* (2022)

Measurements setup

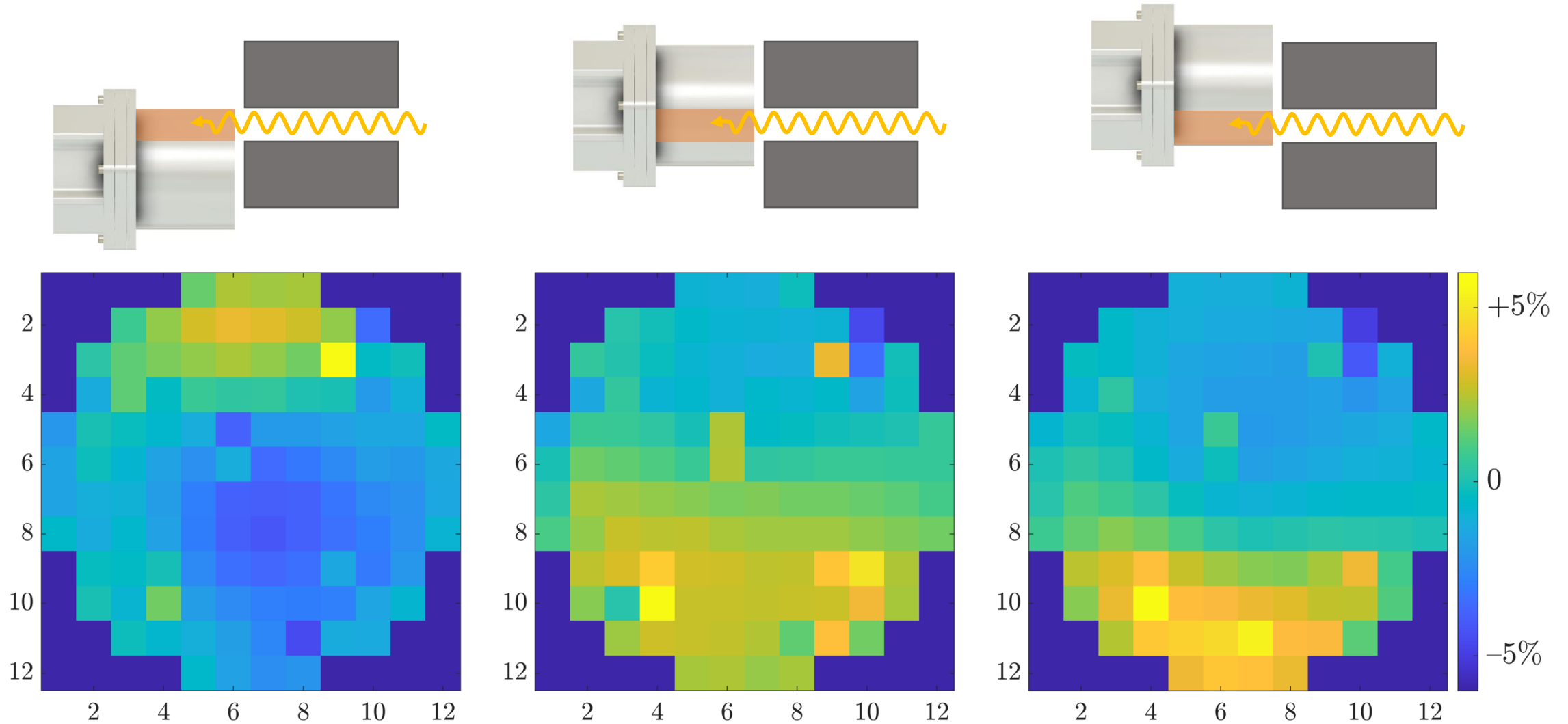
Beamline experiments performed at IFIN-HH Tandem accelerator (Măgurele, Romania)



SiPM+LaBr₃ energy resolution: fixed gain vs AGC

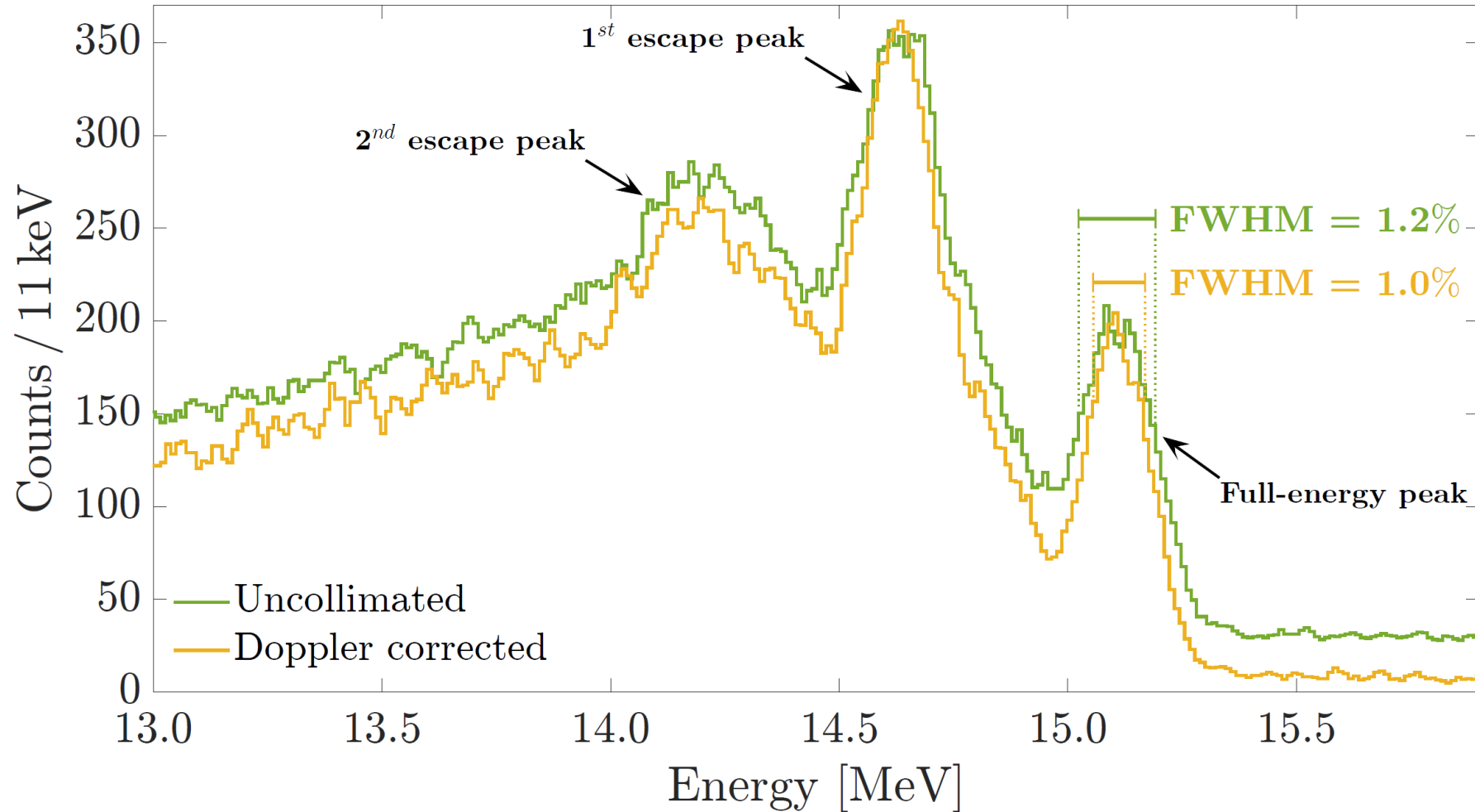


SiPM illumination at 15.1MeV with collimation



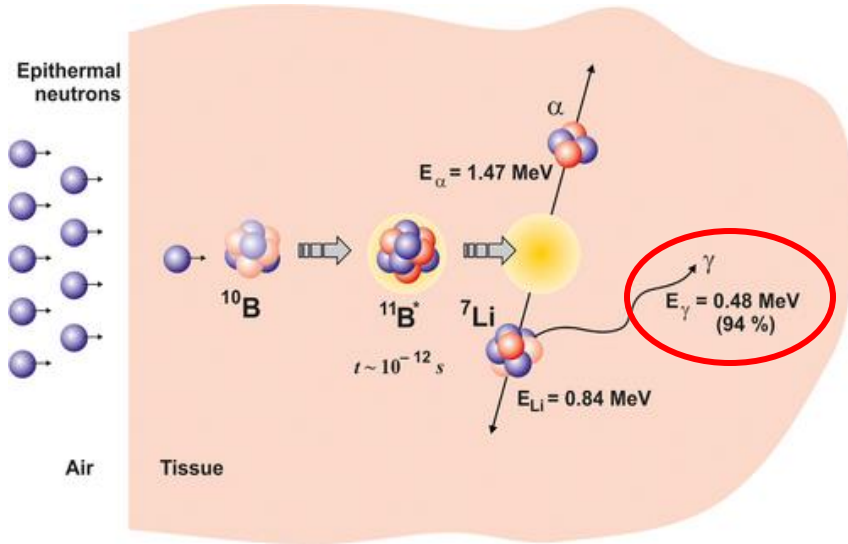
SiPMs signal patterns for different collimations

Uncollimated spectrum corrected for Doppler broadening



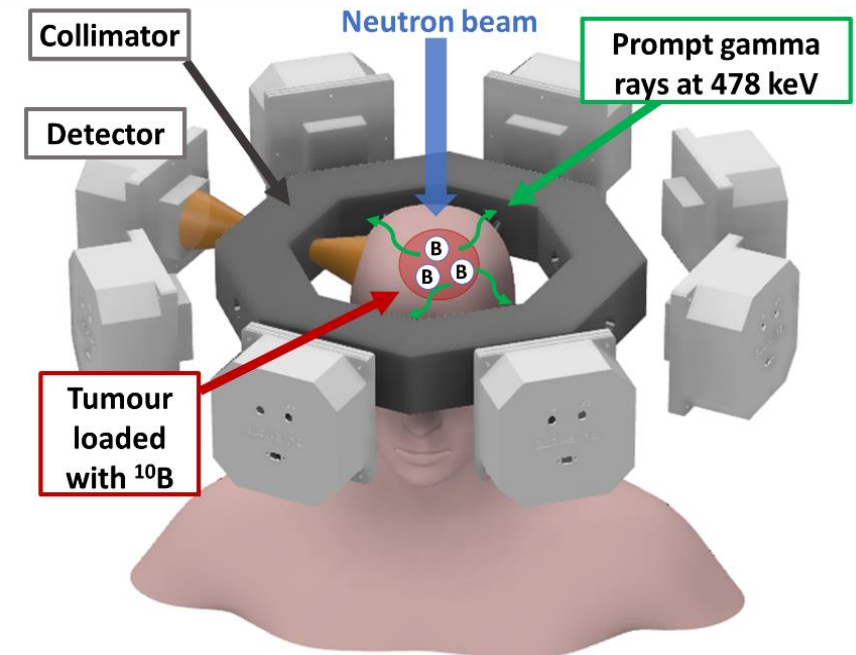
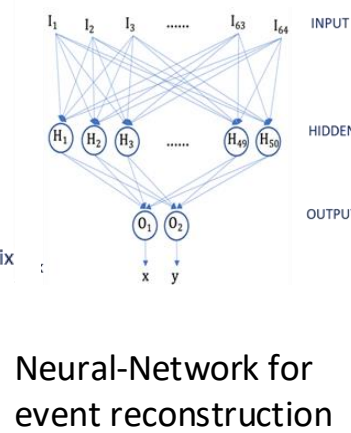
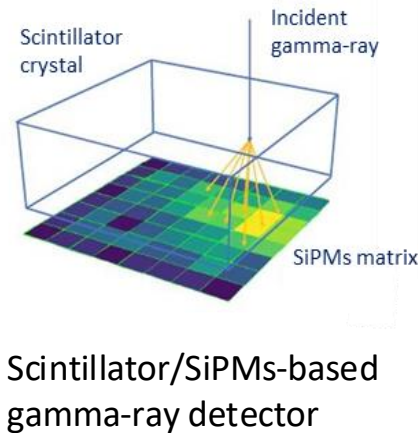
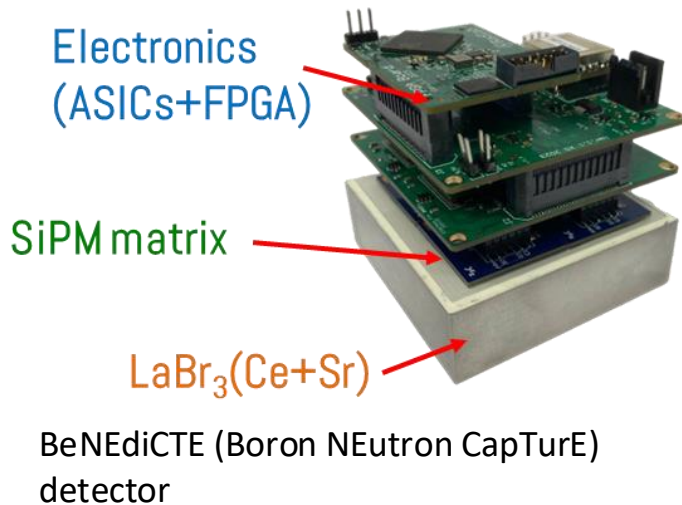
The uncollimated spectrum has been moved upward and recalibrated to be superposed with the corrected one

Application in BNCT (Boron Neutron Capture Therapy)

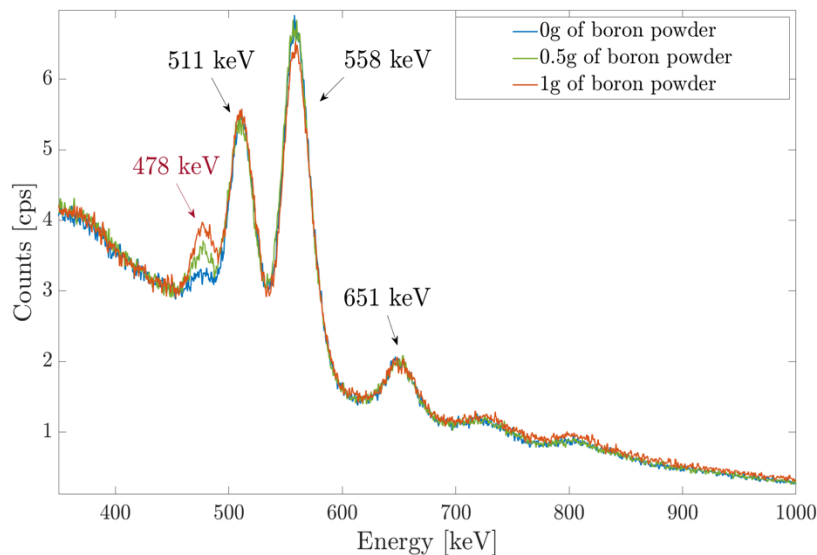
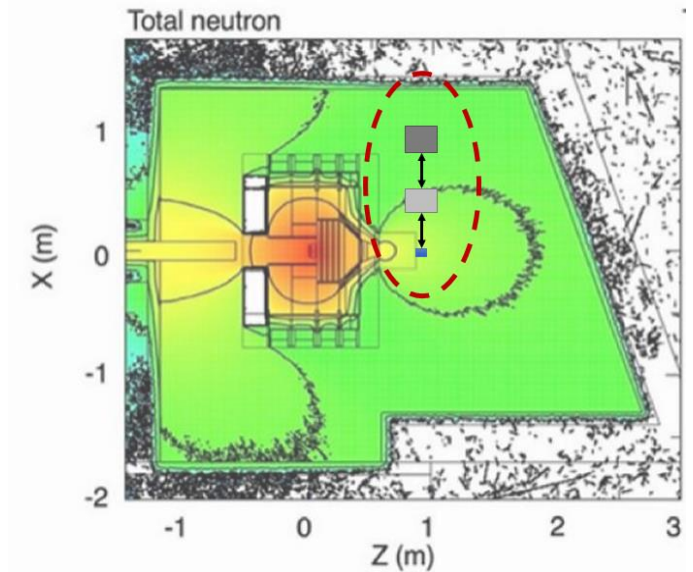
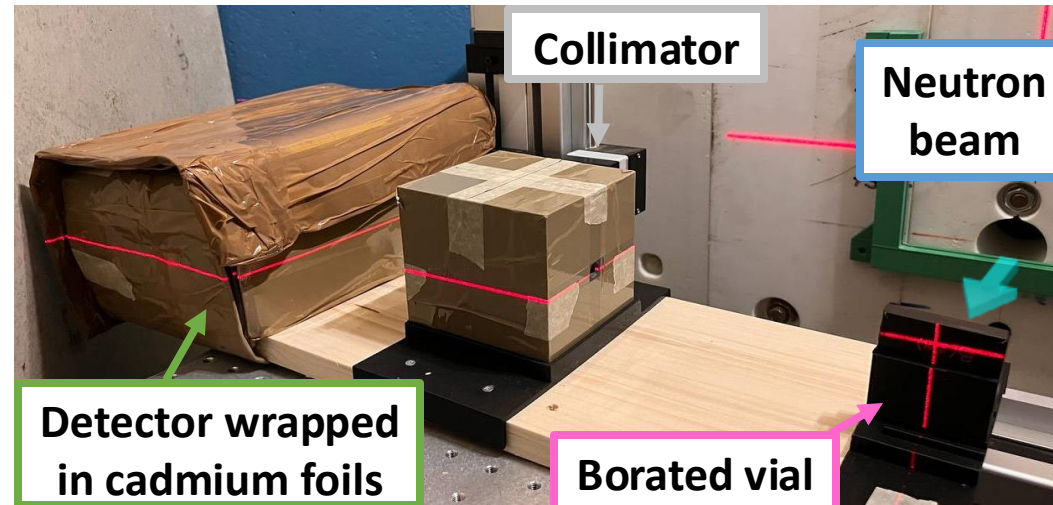


Detection of emitted **478keV gamma photons** may let to estimate ^{10}B neutron captures and support therapeutic outcome (personalized dosimetry).

Goal: Development of a SPECT (Single Photon Emission Thomography) system) for BNCT

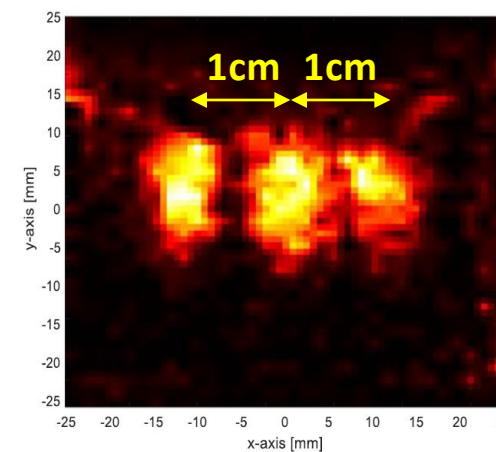


Experiments at nuclear reactor in Pavia (and BNCT facilities)



➔ Spectroscopic Results

Identification of the BNCT photopeak at 478 keV and linear response at different boron quantities



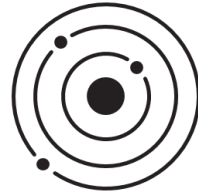
➔ Imaging Results

The ANN algorithm is able to track shifts of 1 cm of the borated sample



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Sezione di Milano



Thanks to Franco and Silvia for
their constant support to this
activity!

Thanks to all of you for your
attention!

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